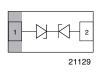
COMPLIANT

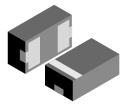
FREE GREEN



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Ultra Low Capacitance Bidirectional Symmetrical (BiSy) Single Line ESD-Protection Diode in LLP1006-2M





20855

MARKING (example only)



Bar = pin 1 marking X = date code

Y = type code (see table below)

FEATURES

- Ultra compact LLP1006-2M package
- Low package height < 0.4 mm
- 1-line ESD-protection
- Working range ± 5.5 V
- Low leakage current < 0.01 μA
- Ultra low load capacitance C_D = 0.36 pF typ.
- ESD-protection acc. IEC 61000-4-2
- ± 18 kV contact discharge
- ± 18 kV air discharge
- Lead plating: Sn (e3)

Tin plated exposed side wall of leadframe.

Soldering can be checked by standard vision inspection.

(AOI = Automated Outgoing Inspection)

No X-ray necessary

- · Lead material: Cu
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

ORDERING INFORMATION				
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY	
VBUS05M1-DD1	VBUS05M1-DD1-G3-08	10 000	100 000	

PACKAGE DATA					
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	SOLDERING CONDITIONS	
VBUS05M1-DD1	LLP1006-2M	5	0.72 mg	260 °C/10 s at terminals reflow soldering according JEDEC® STD-020	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I _{PPM}	4.5	Α	
Peak pulse power	Pin 1 to pin 2 Acc. IEC 61000-4-5; t _p = 8/20 μs; single shot	P _{PP}	95	W	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 18	kV	
	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 18		
Operating temperature	Junction temperature	TJ	-55 to +125	°C	
Storage temperature		T _{stg}	-55 to +150	°C	

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and International patents.

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ESD-PROTECTION FOR HIGH-SPEED SIGNAL OR DATA LINES

The VBUS05M1-DD1 is a Bidirectional and Symmetrical (BiSy) ESD-protection device which clamps positive and negative overvoltage transients to ground. Connected between the signal or data line and the ground the VBUS05M1-DD1 offers a high isolation (low leakage current, low capacitance) within the specified working range. Due to the short leads and small package size of the tiny LLP1006 package the line inductance is very low, so that fast transients like and ESD-strike can be clamped with minimal over- or undershoots. Due to the very low capacitance the VBUS05M1-DD1 can be used for high speed data ports like HDMI, USB 3.0 or Thunderbolt.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	5.5	V
Reverse voltage	at I _R = 0.1 μA	V_R	5.5	-	-	V
Reverse current	at V _{RWM} = 5.5 V	I _R	-	-	0.1	μΑ
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6.0	8.5	10	V
Reverse clamping voltage	at I _{PP} = 1 A	V _C	-	11	13	V
	at I _{PP} = I _{PPM} = 4.5 A	V _C	-	18	21	V
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	-	0.36	0.4	pF
	at V _R = 3.3 V; f = 1 MHz	C _D	-	0.36	-	pF
Clamping voltage	Transmission Line Pulse (TLP); $t_p = 100 \text{ ns}$ $I_{TLP} = 8 \text{ A}$	V	-	21	-	V
	Transmission Line Pulse (TLP); $t_p = 100 \text{ ns}$ $I_{TLP} = 16 \text{ A}$	V _{C-TLP}	-	31	-	
Dynamic resistance	Transmission Line Pulse (TLP); t _p = 100 ns	R _{DYN}	-	1.3	-	Ω

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

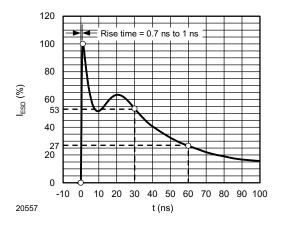


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω /150 pF)

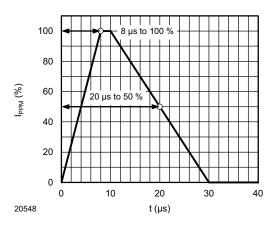


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

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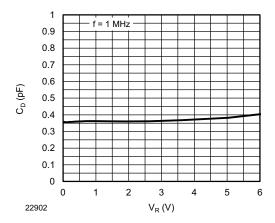


Fig. 3 - Typical Capacitance vs. Reverse Voltage

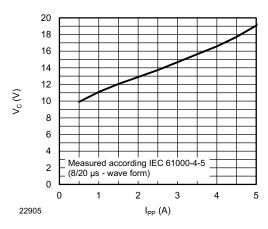


Fig. 6 - Typical Peak Clamping Voltage vs. Peak Pulse Current

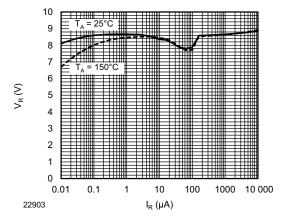


Fig. 4 - Typical Reverse Voltage vs. Reverse Current

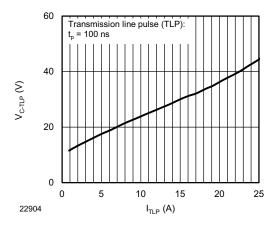
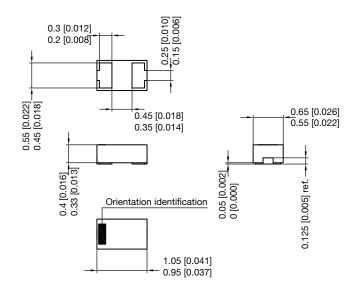


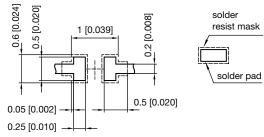
Fig. 5 - Typical Clamping Voltage vs. Peak Pulse Current

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PACKAGE DIMENSIONS in millimeters (inches): LLP1006-2M

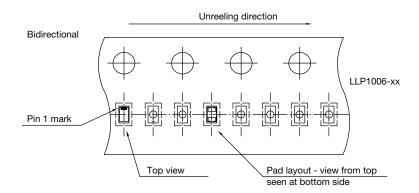


Foot print recommendation:



Pad Design Patented: (PUS 9.018.537 B2)

Document no.: S8-V-3906.04-005 (4) Rev. 7 - Date: 11.May 2016







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